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# SGS10N60RUFD

## 600 V, 10 A Short Circuit Rated IGBT

### General Description

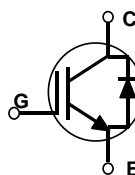
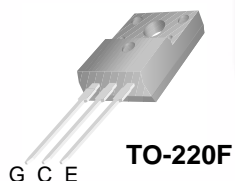
Fairchild's RUF D series of Insulated Gate Bipolar Transistors (IGBTs) provide low conduction and switching losses as well as short circuit ruggedness. The RUF D series is designed for applications such as motor control, uninterrupted power supplies (UPS) and general inverters where short circuit ruggedness is a required feature.

### Features

- 10 A, 600 V,  $T_C = 100^\circ\text{C}$
- Low Saturation Voltage:  $V_{CE(sat)} = 2.2\text{ V @ } I_C = 10\text{ A}$
- Typical Fall Time. . . . .242ns at  $T_J = 125^\circ\text{C}$
- High Speed Switching
- High Input Impedance
- Short Circuit Rating

### Applications

Motor Control, UPS, General Inverter



### Absolute Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Description	SGS10N60RUFD	Unit
$V_{CES}$	Collector-Emitter Voltage	600	V
$V_{GES}$	Gate-Emitter Voltage	$\pm 20$	V
$I_C$	Collector Current @ $T_C = 25^\circ\text{C}$	16	A
	Collector Current @ $T_C = 100^\circ\text{C}$	10	A
$I_{CM(1)}$	Pulsed Collector Current	30	A
$I_F$	Diode Continuous Forward Current @ $T_C = 25^\circ\text{C}$	24	A
	Diode Continuous Forward Current @ $T_C = 100^\circ\text{C}$	12	A
$I_{FM}$	Diode Maximum Forward Current	92	A
$T_{SC}$	Short Circuit Withstand Time @ $T_C = 100^\circ\text{C}$	10	$\mu\text{s}$
$P_D$	Maximum Power Dissipation @ $T_C = 25^\circ\text{C}$	55	W
	Maximum Power Dissipation @ $T_C = 100^\circ\text{C}$	22	W
$T_J$	Operating Junction Temperature	-55 to +150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55 to +150	$^\circ\text{C}$
$T_L$	Maximum Lead Temp. for soldering purposes, 1/8" from case for 5 seconds	300	$^\circ\text{C}$

Notes :  
(1) Repetitive rating : Pulse width limited by max. junction temperature

### Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Unit
$R_{\theta JC}(\text{IGBT})$	Thermal Resistance, Junction-to-Case	--	2.3	$^\circ\text{C/W}$
$R_{\theta JC}(\text{DIODE})$	Thermal Resistance, Junction-to-Case	--	3.7	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	--	62.5	$^\circ\text{C/W}$

**Electrical Characteristics of IGBT**  $T_C = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$BV_{CES}$	Collector-Emitter Breakdown Voltage	$V_{GE} = 0\text{ V}, I_C = 250\text{ }\mu\text{A}$	600	--	--	V
$\frac{\Delta BV_{CES}}{\Delta T_J}$	Temperature Coeff. of Breakdown Voltage	$V_{GE} = 0\text{ V}, I_C = 1\text{ mA}$	--	0.6	--	V/ $^\circ\text{C}$
$I_{CES}$	Collector Cut-off Current	$V_{CE} = V_{CES}, V_{GE} = 0\text{ V}$	--	--	250	$\mu\text{A}$
$I_{GES}$	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0\text{ V}$	--	--	$\pm 100$	nA

**On Characteristics**

$V_{GE(th)}$	G-E Threshold Voltage	$I_C = 10\text{ mA}, V_{CE} = V_{GE}$	5.0	6.0	8.5	V
$V_{CE(sat)}$	Collector to Emitter Saturation Voltage	$I_C = 10\text{ A}, V_{GE} = 15\text{ V}$	--	2.2	2.8	V
		$I_C = 16\text{ A}, V_{GE} = 15\text{ V}$	--	2.5	--	V

**Dynamic Characteristics**

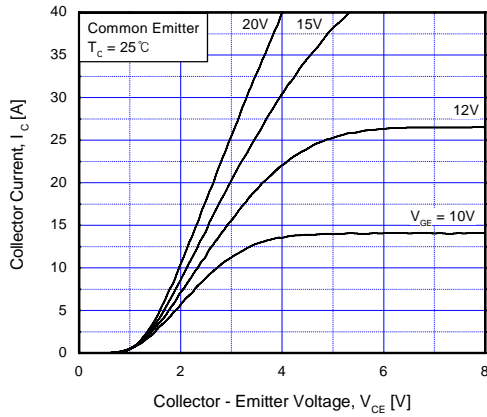
$C_{ies}$	Input Capacitance	$V_{CE} = 30\text{ V}, V_{GE} = 0\text{ V},$ $f = 1\text{ MHz}$	--	660	--	pF
$C_{oes}$	Output Capacitance		--	115	--	pF
$C_{res}$	Reverse Transfer Capacitance		--	25	--	pF

**Switching Characteristics**

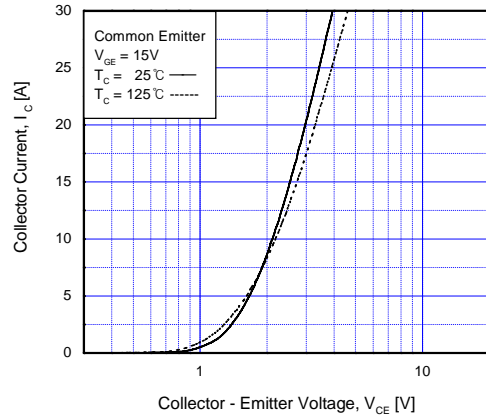
$t_{d(on)}$	Turn-On Delay Time	$V_{CC} = 300\text{ V}, I_C = 10\text{ A},$ $R_G = 20\text{ }\Omega, V_{GE} = 15\text{ V},$ Inductive Load, $T_C = 25^\circ\text{C}$	--	15	--	ns
$t_r$	Rise Time		--	30	--	ns
$t_{d(off)}$	Turn-Off Delay Time		--	36	50	nS
$t_f$	Fall Time		--	158	200	ns
$E_{on}$	Turn-On Switching Loss		--	141	--	$\mu\text{J}$
$E_{off}$	Turn-Off Switching Loss	--	215	--	$\mu\text{J}$	
$E_{ts}$	Total Switching Loss	--	356	500	$\mu\text{J}$	
$t_{d(on)}$	Turn-On Delay Time	$V_{CC} = 300\text{ V}, I_C = 10\text{ A},$ $R_G = 20\text{ }\Omega, V_{GE} = 15\text{ V},$ Inductive Load, $T_C = 125^\circ\text{C}$	--	16	--	ns
$t_r$	Rise Time		--	33	--	ns
$t_{d(off)}$	Turn-Off Delay Time		--	42	60	ns
$t_f$	Fall Time		--	242	350	ns
$E_{on}$	Turn-On Switching Loss		--	161	--	$\mu\text{J}$
$E_{off}$	Turn-Off Switching Loss	--	452	--	$\mu\text{J}$	
$E_{ts}$	Total Switching Loss	--	613	860	$\mu\text{J}$	
$T_{sc}$	Short Circuit Withstand Time	$V_{CC} = 300\text{ V}, V_{GE} = 15\text{ V}$ @ $T_C = 100^\circ\text{C}$	10	--	--	$\mu\text{s}$
$Q_g$	Total Gate Charge	$V_{CE} = 300\text{ V}, I_C = 10\text{ A},$ $V_{GE} = 15\text{ V}$	--	30	45	nC
$Q_{ge}$	Gate-Emitter Charge		--	5	10	nC
$Q_{gc}$	Gate-Collector Charge		--	8	16	nC
$L_e$	Internal Emitter Inductance	Measured 5mm from PKG	--	7.5	--	nH

**Electrical Characteristics of DIODE**  $T_C = 25^\circ\text{C}$  unless otherwise noted

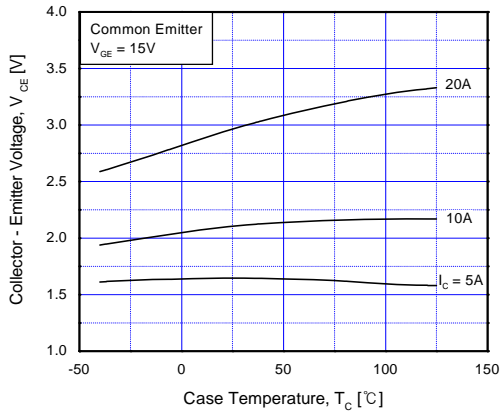
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit	
$V_{FM}$	Diode Forward Voltage	$I_F = 12\text{ A}$	$T_C = 25^\circ\text{C}$	--	1.4	1.7	V
			$T_C = 100^\circ\text{C}$	--	1.3	--	
$t_{rr}$	Diode Reverse Recovery Time	$I_F = 12\text{ A},$ $di_F/dt = 200\text{ A}/\mu\text{s}$	$T_C = 25^\circ\text{C}$	--	42	60	ns
			$T_C = 100^\circ\text{C}$	--	60	--	
$I_{rr}$	Diode Peak Reverse Recovery Current	$I_F = 12\text{ A},$ $di_F/dt = 200\text{ A}/\mu\text{s}$	$T_C = 25^\circ\text{C}$	--	3.5	6.0	A
			$T_C = 100^\circ\text{C}$	--	5.6	--	
$Q_{rr}$	Diode Reverse Recovery Charge	$I_F = 12\text{ A},$ $di_F/dt = 200\text{ A}/\mu\text{s}$	$T_C = 25^\circ\text{C}$	--	80	180	nC
			$T_C = 100^\circ\text{C}$	--	220	--	



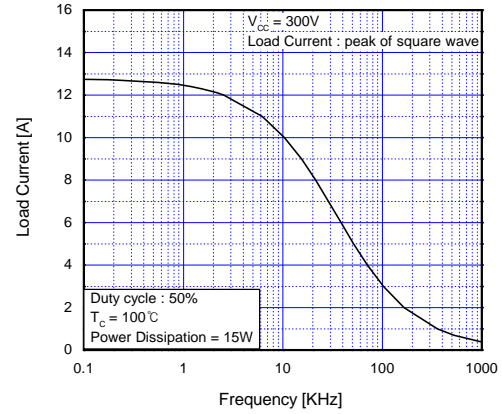
**Fig 1. Typical Output Characteristics**



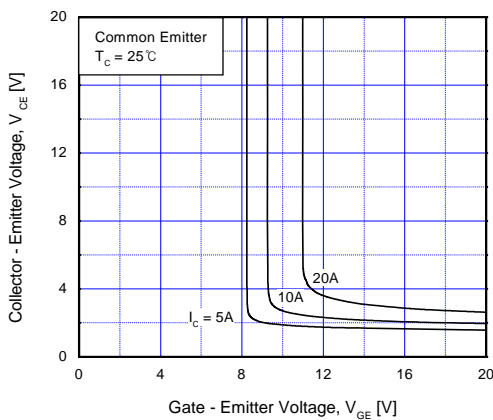
**Fig 2. Typical Saturation Voltage Characteristics**



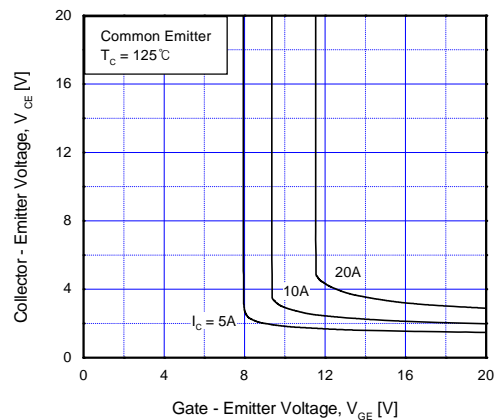
**Fig 3. Saturation Voltage vs. Case Temperature at Variant Current Level**



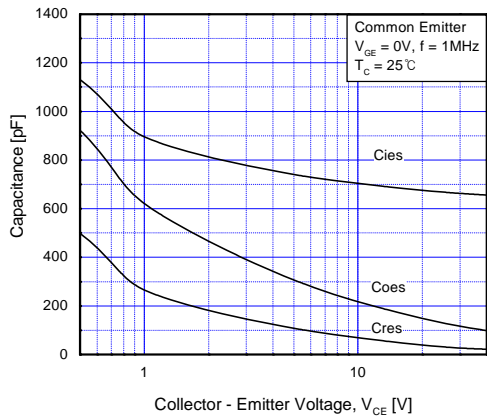
**Fig 4. Load Current vs. Frequency**



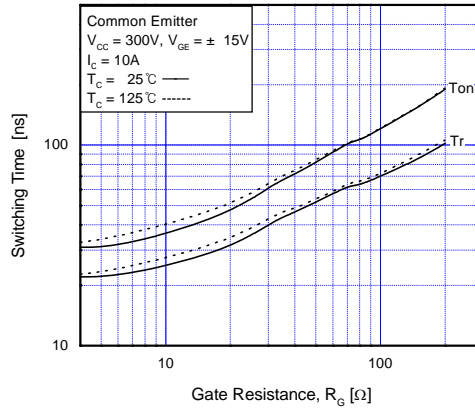
**Fig 5. Saturation Voltage vs.  $V_{GE}$**



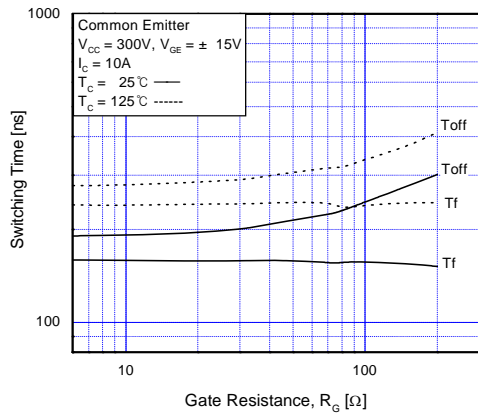
**Fig 6. Saturation Voltage vs.  $V_{GE}$**



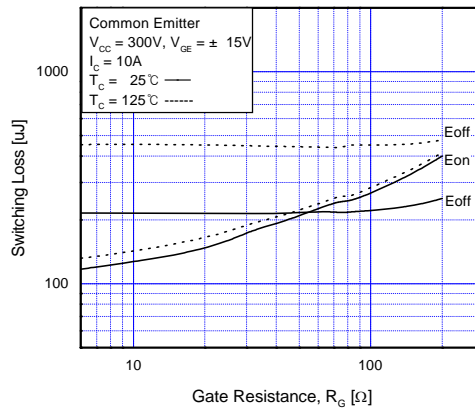
**Fig 7. Capacitance Characteristics**



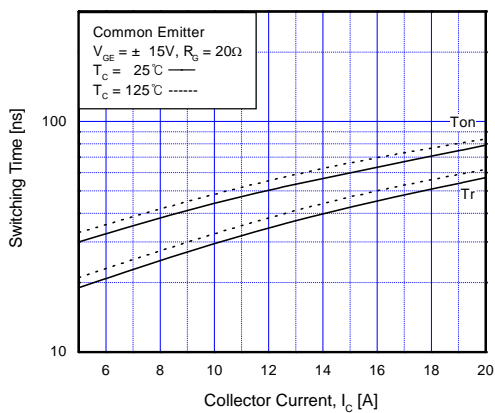
**Fig 8. Turn-On Characteristics vs. Gate Resistance**



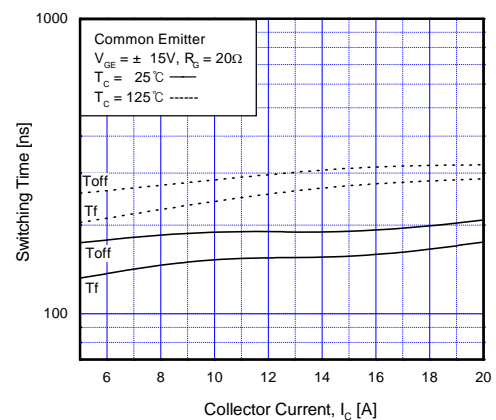
**Fig 9. Turn-Off Characteristics vs. Gate Resistance**



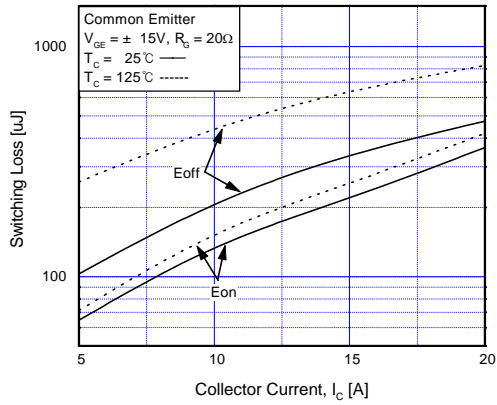
**Fig 10. Switching Loss vs. Gate Resistance**



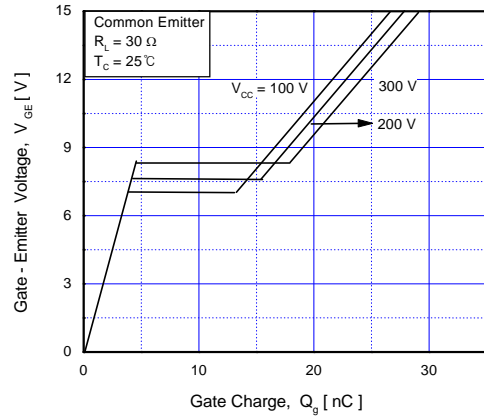
**Fig 11. Turn-On Characteristics vs. Collector Current**



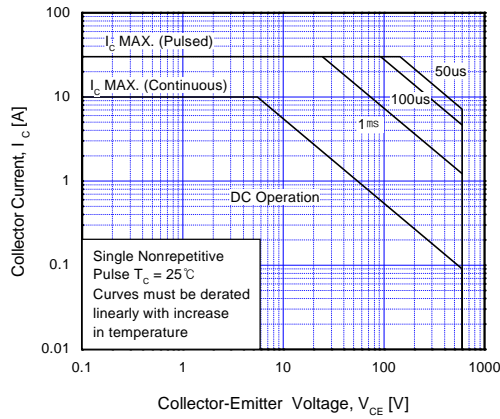
**Fig 12. Turn-Off Characteristics vs. Collector Current**



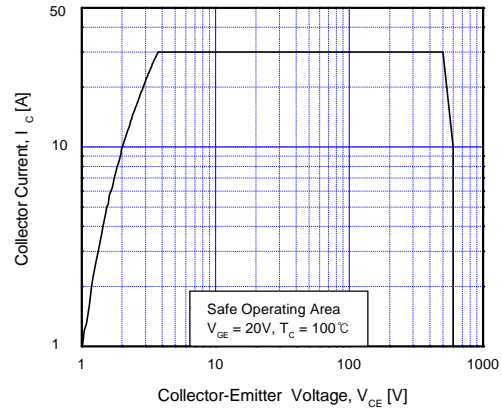
**Fig 13. Switching Loss vs. Collector Current**



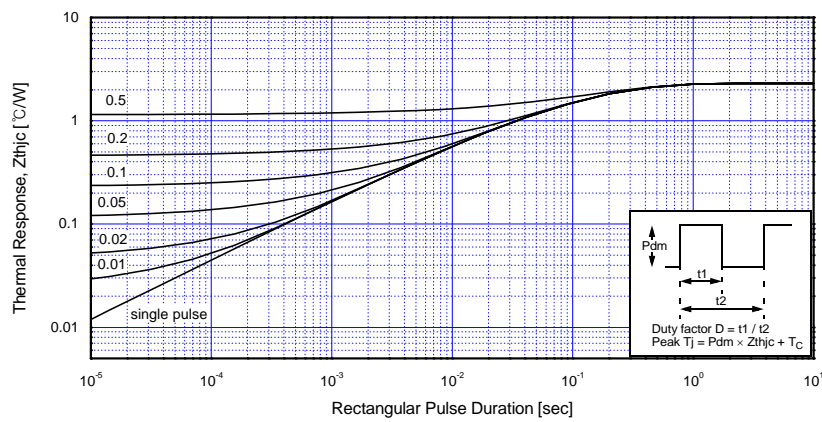
**Fig 14. Gate Charge Characteristics**



**Fig 15. SOA Characteristics**



**Fig 16. Turn-Off SOA Characteristics**



**Fig 17. Transient Thermal Impedance of IGBT**

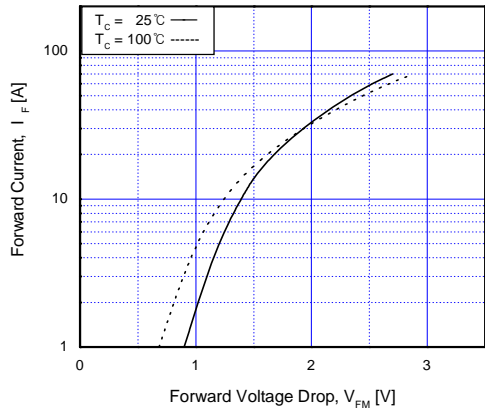


Fig 18. Forward Characteristics

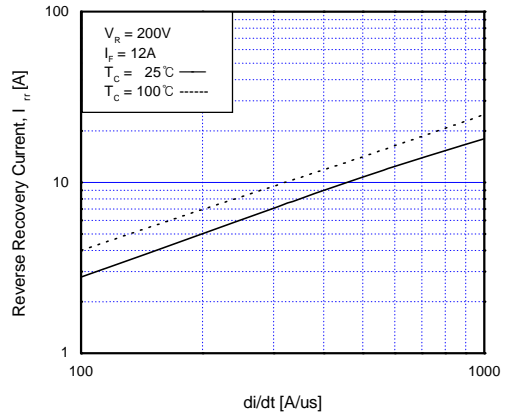


Fig 19. Reverse Recovery Current

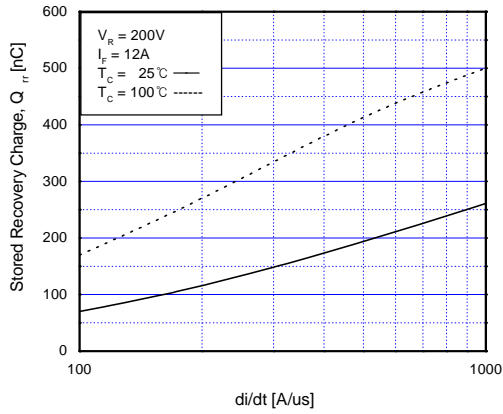


Fig 20. Stored Charge

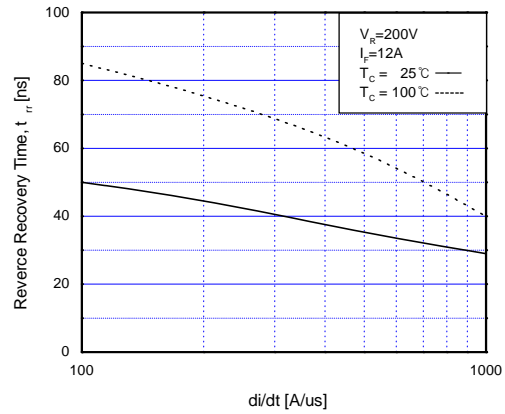
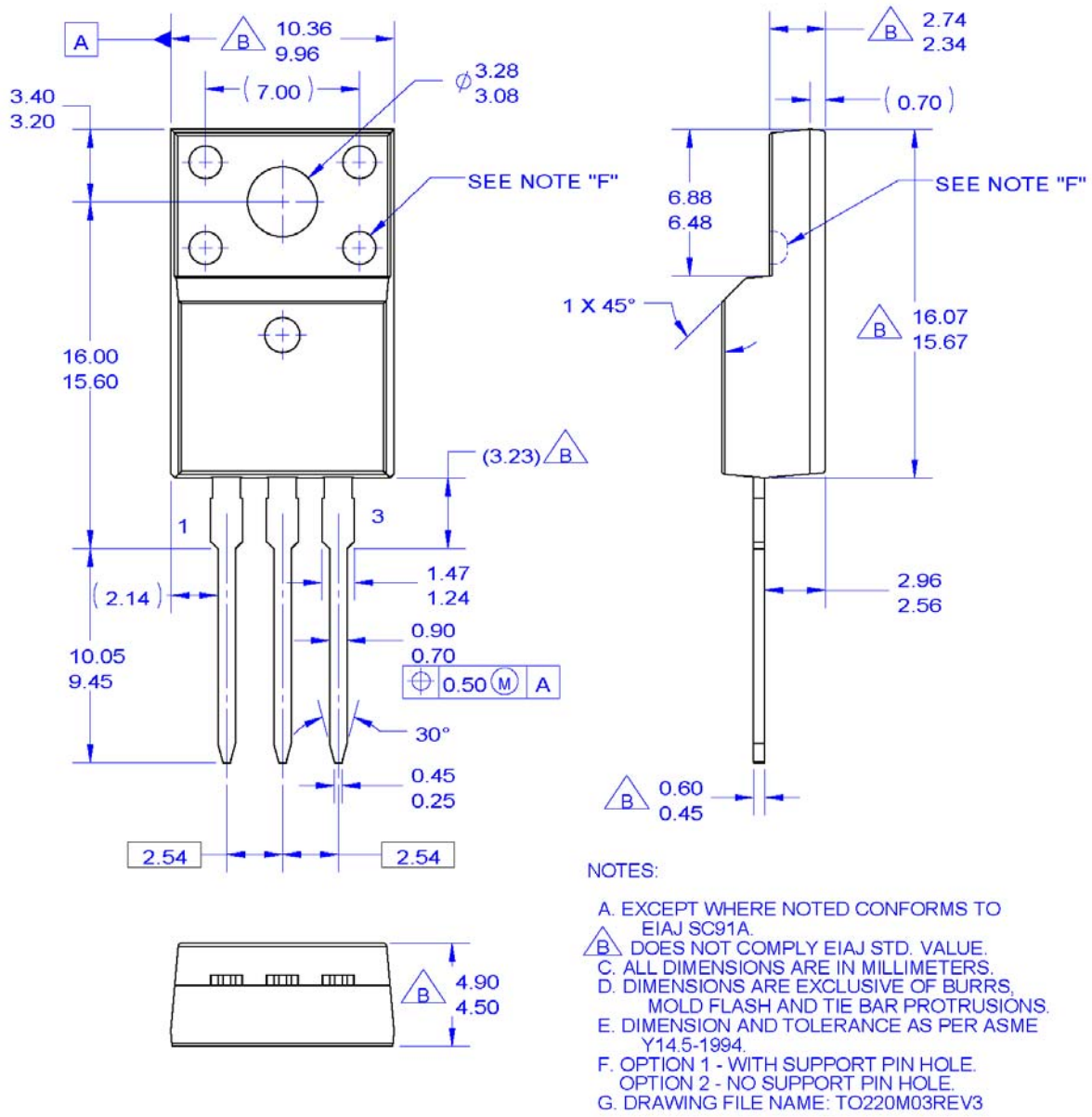


Fig 21. Reverse Recovery Time

**Package Dimensions**



**Figure 22. TO-220F 3L - TO220, MOLDED, 3LD, FULL PACK, EIAJ SC91, STRAIGHT LEAD**

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